## NSN 5962-01-226-4355

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high to low level

View Online at https://aerobasegroup.com/nsn/5962-01-226-4355

Body Length	
0.840 inches	
Body Width:	
Between 0.22	0 inches and 0.310 inches
Body Height:	
0.185 inches	
Maximum Po	wer Dissipation Rating:
794.0 milliwat	S
Operating Te	mpurature Range:
-55.0/+125.0 (	legrees celsius
Storage Tem	purature Range:
-65.0/+150.0 (	legrees celsius
End Applicat	ion:
An/bps14to15	e
Features Pro	vided:
Hermetically s	ealed and burn in and programmable and bipolar and schottky
Inclosure Ma	terial:
Ceramic	
Inclosure Co	nfiguration:
Dual-in-line	
Output Logic	Form:
Transistor-trai	nsistor logic
Input Circuit	Pattern:
10 input	
Case Outline	Source And Designator:
D-2 mil-m-385	10
Terminal Sur	face Treatment:
Solder	
Voltage Ratir	g And Type Per Characteristic:
-0.5 volts pov	ver source and 7.0 volts power source
Time Rating	Per Chacteristic:
85.00 nanose	conds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, I
output	
Memory Devi	се Туре:
Prom	
Memory Capa	acity:
Unknown	
Test Data Do	cument:
96906-mil-std	883 standard (includes industry or association standards, individual manufactureer standards, etc.).
	e And Quantity:
16 printed circ	
Shelf Life:	
N/a	

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

